

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	275195	((ionic near5 conduct\$3) electrolyte (metal near5 containing) chalcogenic chalcogenide)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:56
L2	298309	((upper top) near5 electrode) anode	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:56
L3	383004	((lower bottom) near5 electrode) cathode	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:56
L4	244584	2 and 3	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:52
L5	54048	1 and 4	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:53
L6	9877	5 and (insult\$3 dielectric)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:57
L7	7096	6 and (silver tungsten copper germanium selenium selenide)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:57
L8	642	7 and (PMRAM microelectronic PCRAM programmable)	US-PGPU B; USPAT; USOCR	OR	ON	2005/07/29 15:58
L9	277675	((ionic near5 conduct\$3) electrolyte (metal near5 containing) chalcogenic chalcogenide)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:56
L10	212141	((upper top) near5 electrode) anode	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:56
L11	262573	((lower bottom) near5 electrode) cathode	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:56
L12	133658	10 and 11	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:56
L13	26994	12 and 9	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:57

L14	1005	13 and (insult\$3 dielectric)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:57
L15	115	14 and (silver tungsten copper germanium selenium selenide)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:57
L16	1	14 and (PMRAM micoelectronic PCRAM programmable)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:58
L17	116	15 16	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/29 15:58